808nm Narrow Linewidth Laser System of NLM Series





Model		CL808-MIF(S)-500mW-NLM008	CL808-MIF(FP)-500mW-NLM009
	Central Wavelength (nm)	808	808
	Output Power (mW)	500	500
	Wavelength Tolerance (nm)	±0.5	±0.5
Optical Parameter	Line Width (nm)	<0.1	<0.1
	Wavelength Stability	±0.005nm @8H Typ.	±0.005nm @8H Typ.
	Power Stability	±1.5% @8H Typ.	±1.5% @8H Typ.
	Edge Mode Rejection Ratio (dB)	40	40
System Parameter	Power Adjustment Range	0~100%	0~100%
	Preheat Time (min)	15	15
	Modulation Input	1kHz TTLOr Analog signal0-5V	1kHz TTLOr Analog signal0-5V
	Control Interface	USB, BNC	USB, BNC
	Fiber Interface	SMA905	FC/PC
	Adaptive Optical Fiber	105μm, 0.22NA	105μm, 0.22NA
	Power Input	100V-240V 50/60Hz	100V-240V 50/60Hz
	System Power Consumption (W)) <7	<7
	Storage Temperature (℃)	-10~60	-10~60
	Storage Humidity	0~80%RH	0~80%RH
	Operating Temperature (℃)	10~35	10~35
	System Weight (Kg)	2.5	2.5
	Laser Power Size (mm)	150 x 102 x 200	150 x 102 x 200

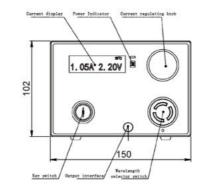
DESCRIPTION

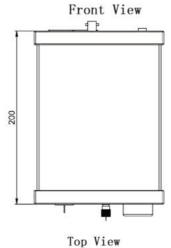
Narrow linewidth laser system is our special product. This series of products are compact in structure, portable and convenient. The core technologies such as short cavity method, VBG wavelength locking, directional optical feedback, built-in semiconductor refrigeration, etc. are used to realize narrow linewidth, stable power and stable spectral output of laser.

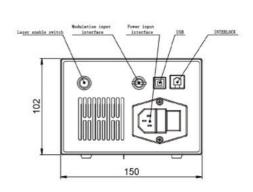
FEATURES

- Line width <0.1nm
- Frequency stability better than ±0.005nm@8H
- Side mode rejection ratio is better than 40dB (60dB optional)
 Portable operation, temperature drift <0.007nm / °C, VBG wave lock
- Built-in TEC, power stability is better than ± 1%
- Including host computer control, emergency stop switch, short circuit protection and other functions

OUTLINE SIZE(mm)







Rear View



APPLICATIONS

- Raman spectroscopy
- Fluorescence spectrum detection
- Holographic detection
- Up-conversion material

